

ISL9238EVAL1Z

Evaluation Board User Guide

UG074
Rev.2.00
Nov 14, 2018

Description

The [ISL9238](#) is a buck-boost Narrow Output Voltage DC (NVDC) charger that uses the Renesas advanced R3™ Technology to provide high light-load efficiency, fast transient response, and seamless DCM/CCM transitions for a variety of mobile and industrial applications.

In Charge mode, the ISL9238 takes input power from a wide range (4V to 20V) of DC power sources (conventional AC/DC charger adapters, USB PD ports, travel adapters, etc.) and safely charges battery packs with up to four cells in a series configuration.

The ISL9238 has an On-the-Go (OTG) function for 2- and 4-cell battery applications. When the OTG function is enabled, the ISL9238 operates in Reverse Buck mode to provide 5V at the USB port.

The ISL9238 provides serial communication with SMBus/I²C that allows programming of critical parameters to deliver a customized solution. The programmable parameters include, but are not limited to: adapter current limit, charger current limit, system voltage setting, and trickle charging current limit.

The ISL9238EVAL1Z evaluation board demonstrates the performance of the ISL9238. The default value numbers of the battery in series, switching frequency, and the adapter current limit charging function can be programmed by the resistor from the PROG pin to GND. The values also can be set by SMBus.

Related Literature

For a full list of related documents, refer to our website:

- [ISL9238](#) datasheet

Key Features

- Buck-boost NVDC charger for 1-, 2-, 3-, 4-cell Li-ion batteries
- End of Charge (EOC) option
- System power monitor PSYS output, IMVP-8 compliant
- PROCHOT# open-drain output, IMVP-8 compliant
- Allows trickle charging of depleted battery
- Optional ASGATE FET control
- Ideal diode control in Turbo mode
- Reverse buck, boost, and buck-boost operation from battery
- Two-level adapter current limit available
- Battery Ship mode option
- SMBus and auto-increment I²C compatible

Specifications

- V_{IN} = 3.8V to 24V (no dead zone)
- V_{OUT} = 2.5V to 12.6V
- MAX I_{charge} up to 6A
- f_{sw} = 1MHz maximum

Ordering Information

PART NUMBER	DESCRIPTION
ISL9238EVAL1Z	ISL9238 buck-boost charger evaluation board

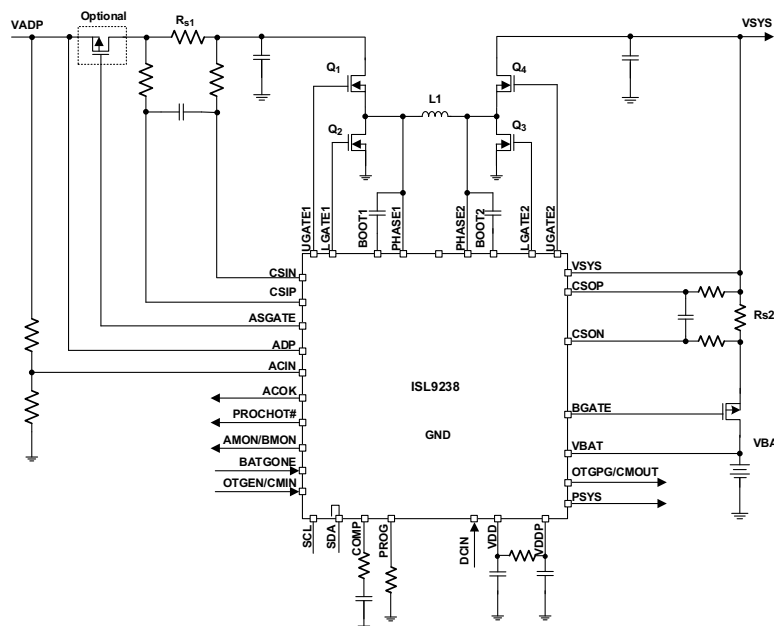


FIGURE 1. BLOCK DIAGRAM

Recommended Equipment

- 0V to 25V power supply with at least 6A source current capability
- Electronic load capable of sinking current up to 6A
- Battery emulator capable of sinking and sourcing current up to 6A
- Digital Multimeters (DMMs)
- 100MHz quad-trace oscilloscope

NOTE: You can use a power supply (that can source current but cannot sink current) in parallel with an e-load Constant Current (CC) mode to emulate the battery. For example, to charge, set the charging current command lower than the CC mode e-load. If the e-load CC mode current is set to 3A, the charge current command is 2A, and the e-load takes 2A from the charger and takes another 1A from the power supply in parallel with it. To discharge, the power supply acts like the battery to discharge current. You can also use the e-load Constant Voltage (CV) mode to emulate the battery to take the charging current from the charger and set the e-load CV voltage below the MaxSysV register setting; however, this e-load CV mode cannot source current like a battery.

Functional Description

The ISL9238EVAL1Z provides all circuits required to evaluate the features of the ISL9238. A majority of the features of the ISL9238, such as adjustable output voltage, On-the-Go (OTG) mode, Trickle Charging mode for depleted battery, and system power monitor at Buck, Boost, and Buck-Boost modes are available on this evaluation board.

Quick Start Guide

The number of battery cell and adapter current limit default values can be configured with a standard 1% 0603 resistor (R_{23}) from the PROG pin to GND. The "PROG PIN PROGRAMMING OPTIONS" table in the [ISL9238](#) datasheet shows the programming options. After the default number of cells in series is set, the default values for MaxSystemVoltage and MinSystemVoltage are set accordingly. These values can also be changed through the SMBus control registers in the Renesas GUI, shown in [Figure 2 on page 3](#).

The three LEDs indicate the ACOK, PROCHOT, and OTGPG/CMOUT status, respectively. For more details about the functions of these three pins, refer to the [ISL9238](#) datasheet. Complete the following steps to evaluate the ISL9238 key functions, including system voltage regulation, input current limit regulation, Charging mode, trickle Charging mode, and OTG mode. [Figure 3](#) shows the top view of the evaluation board and highlights the key testing points and connection terminals. For more information about the ISL9238, including other modes of operation, refer to the [ISL9238](#) datasheet.

System Voltage Regulation

1. Set the power supply to 5V. Disable the output and connect the (+) end to J1 and the (-) end to J2.
2. Ensure jumpers JP3, JP4, and JP6 are shorted. SW1 and SW2 should switch to the low position.
3. Turn on the power supply and measure VSYS using the DMM across (+) and (-) TP5. VSYS should read 8.38V. The current meter on the supply should read <100mA. Slowly increase V_{IN} from 5V to 15V. Monitor PH1 and PH2 to observe seamless switching from Boost mode to Buck-Boost mode and finally into Buck mode.

Input Current Limit Regulation

1. Keep V_{IN} as a constant value between 3.8V and 24V. Set the battery emulator voltage to 7.8V and connect the battery emulator output to battery leads J5 and J6. Turn on the battery emulator; there is no charge and discharge current for the battery, which is consistent with the BGATE signal of a high voltage level.
2. Add an electrical load on VSYS and GND terminals J3 and J4. Turn on the load and increase the electrical load slowly; the input current increases correspondingly and VSYS keeps stable at 8.38V. The output voltage (VSYS) starts dropping as the input current reaches the 1.5A input current limit. Refer to the [ISL9238](#) datasheet for more information about the input current limit. If the VSYS voltage is 150mV lower than the battery voltage, the BGATE FET turns on at a low voltage level so that the battery supplies the current to the load.

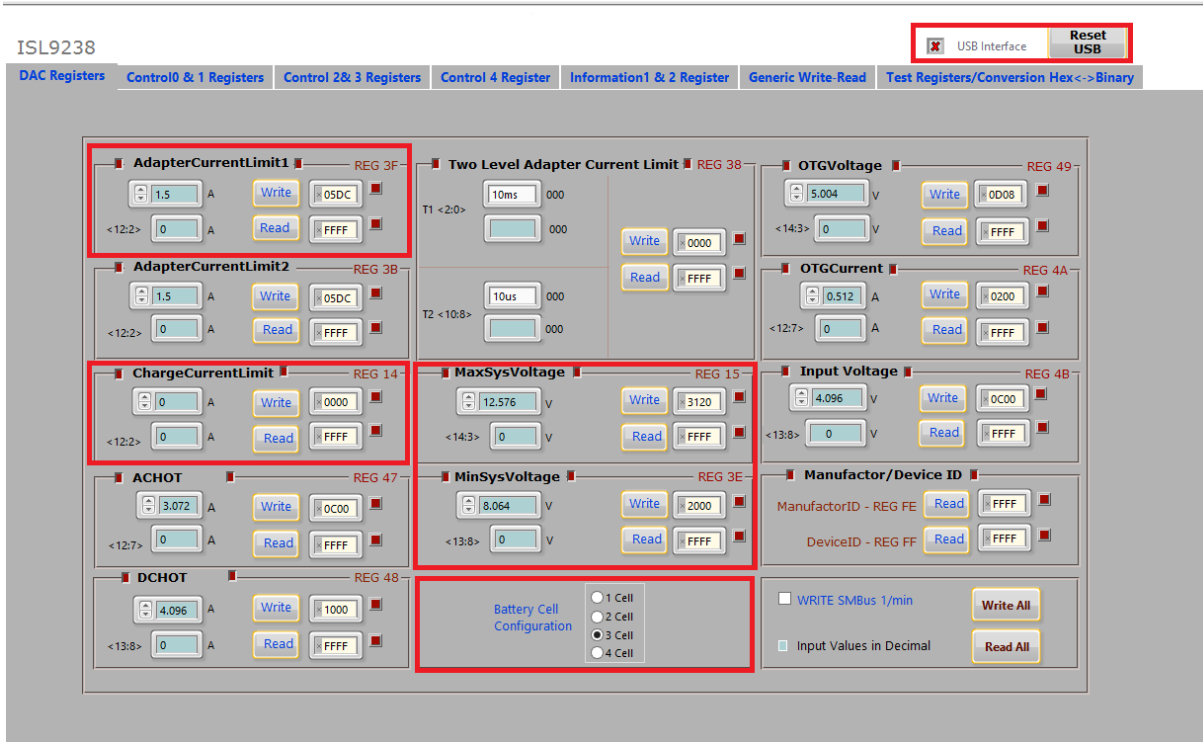


FIGURE 2. GUI SNAPSHOT

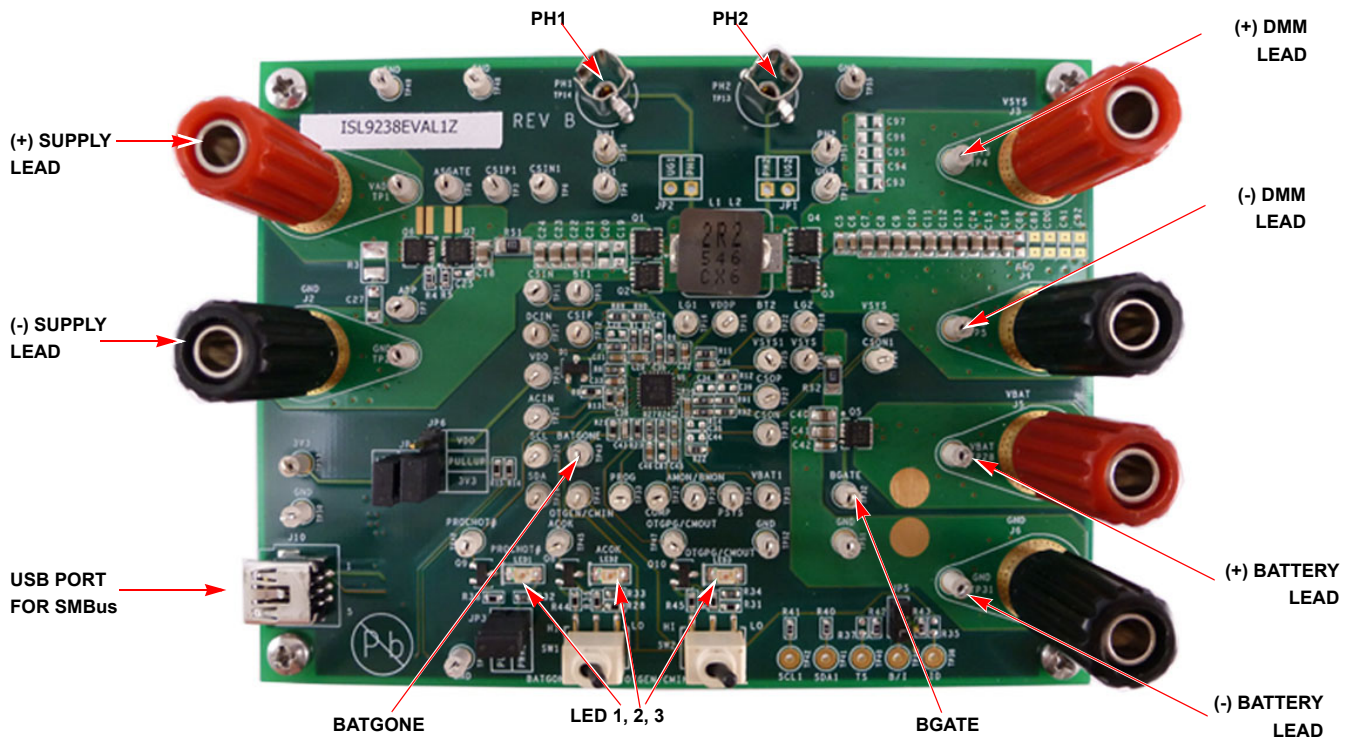




FIGURE 3. EVALUATION BOARD CONNECTION GUIDELINE

Charging Mode

1. Set the power supply to a constant value between 3.8V and 24V, then complete Steps 1 and 2 in "[System Voltage Regulation](#)" on page 2. Make sure the input current does not reach the limit.
2. Set the battery emulator voltage to 7.8V and connect the battery emulator output to battery leads J5 and J6.
3. Connect the USB cable at the USB port for the SMBus. LED 1, 2, and 3 all turn on.
4. Turn on the power supply; LED 3 turns off. Turn on the battery emulator and open the ISL9238 GUI (shown in [Figure 2 on page 3](#)).

Note: A green check mark  in the **USB Interface** section of the GUI indicates the GUI is ready to communicate with the evaluation board. A red X  in the **USB Interface** section indicates the GUI is not ready to communicate with the evaluation board. Click the **Reset USB** button until a green check mark shows in the **USB Interface**. If a green check mark does not appear, check the USB connection.

5. Select **2 Cell** in the **Battery Cell Configuration** section and click the **Write All** button. All controller register values are set to the default values correspondingly. The system voltage is 8.4V, which is the value of **MaxSysVoltage** in the GUI. There is no charge and discharge current for the battery.
6. Change the **ChargeCurrentLimit** from **0A** to **2A** and click the **Write** button. The battery is now in a 2A current charge configuration. The charge current value can be monitored in the GUI by clicking the **Read** button in the **ChargeCurrentLimit** section. Monitor the BGATE signal status to confirm the battery is in Charging mode.

Note: Make sure the input current does not reach the input current limit value, especially for a small V_{IN} input.

Trickle Charging Mode

1. Complete Steps 1 through 6 in "[Charging Mode](#)" without any changes.
2. Decrease the battery emulator voltage and monitor the battery charging current. As long as the battery emulator voltage is less than 5.2V (lower than SystemMinVoltage), the battery enters trickle Charging mode and the charge current decreases to 0.26A. The trickle charge current value can be changed through the SMBus control registers. Refer to the [ISL9238](#) datasheet for more information.

Note: Make sure the input current does not reach the input current limit value, especially for small V_{IN} input.

OTG Mode

1. Set the battery emulator voltage to a constant value between 5.8V and 15V. Connect battery leads J5 and J6 with the output disabled.
2. Connect the electric load on supply leads J1 and J2 with the output disabled.
3. Connect the USB cable at the USB port for SMBus. Only the LED 1 light is on. Turn on the battery emulator and electrical load without adding any load.
4. Open the ISL9238 GUI. The **OTGVoltage** is the voltage value for the load side, as shown in [Figure 4 on page 5](#). The **OTGCurrent** is the OTG output current limit at the load side. These values can be set as needed within the output limit range. Refer to the [ISL9238](#) datasheet for the **OTGVoltage** and **OTGCurrent** value ranges.
5. Select the **Control0 & 1 Registers** tab, enable the OTG function in **Control1 Register**, and click the **Write** button, as shown in [Figure 5 on page 5](#).
6. Switch SW2 on the evaluation board to the HI position. The load voltage is regulated as an OTGVoltage value, set in [Figure 4 on page 5](#), and the LED 3 light is on, indicating the OTG function is enabled.
7. Increase the electrical load slowly and monitor the load voltage. As long as the load current is less than the OTGCurrent limit value, the load voltage is regulated at the set value.

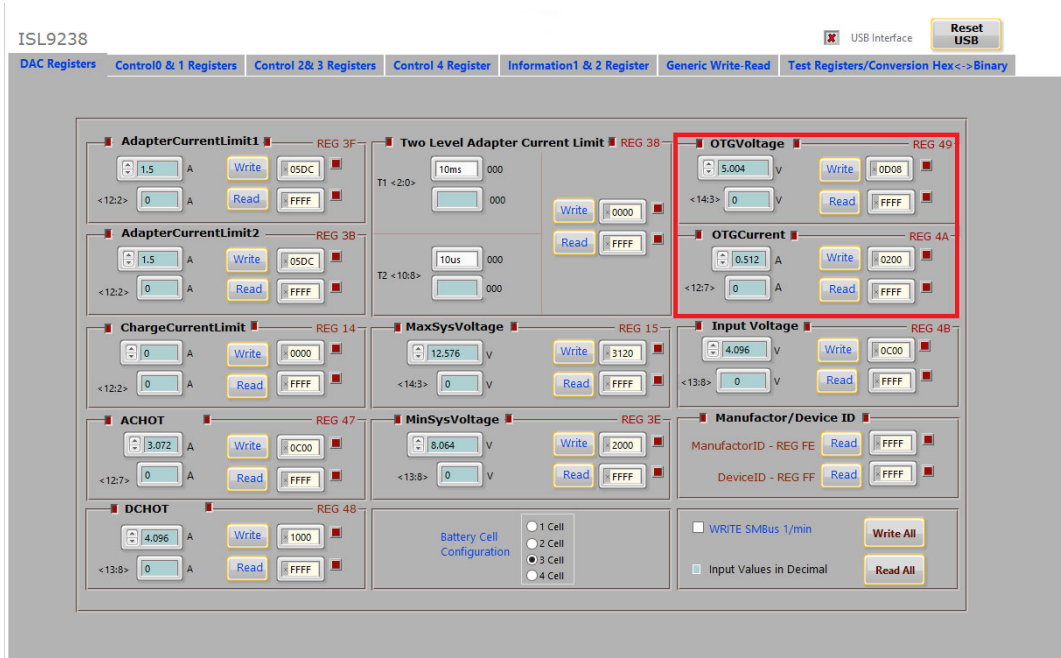


FIGURE 4. OTGVOLTAGE AND OTGCURRENT SETTINGS IN THE GUI

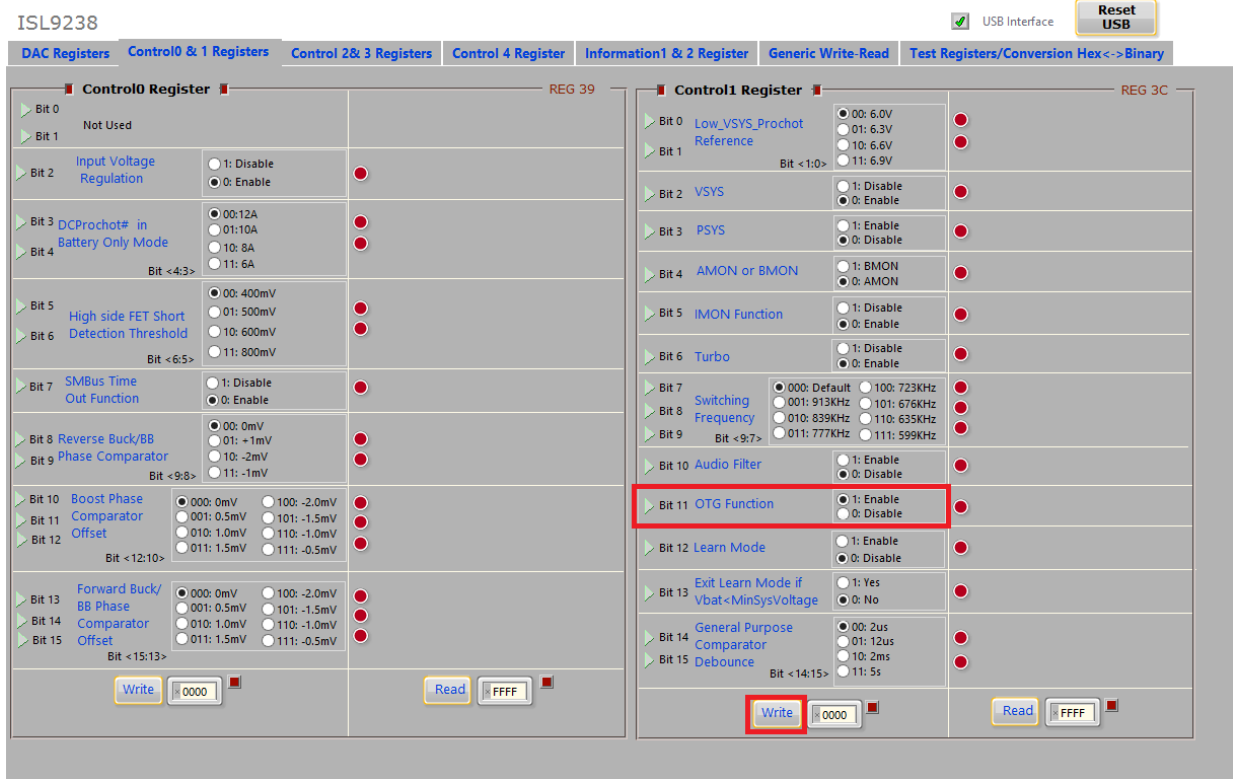
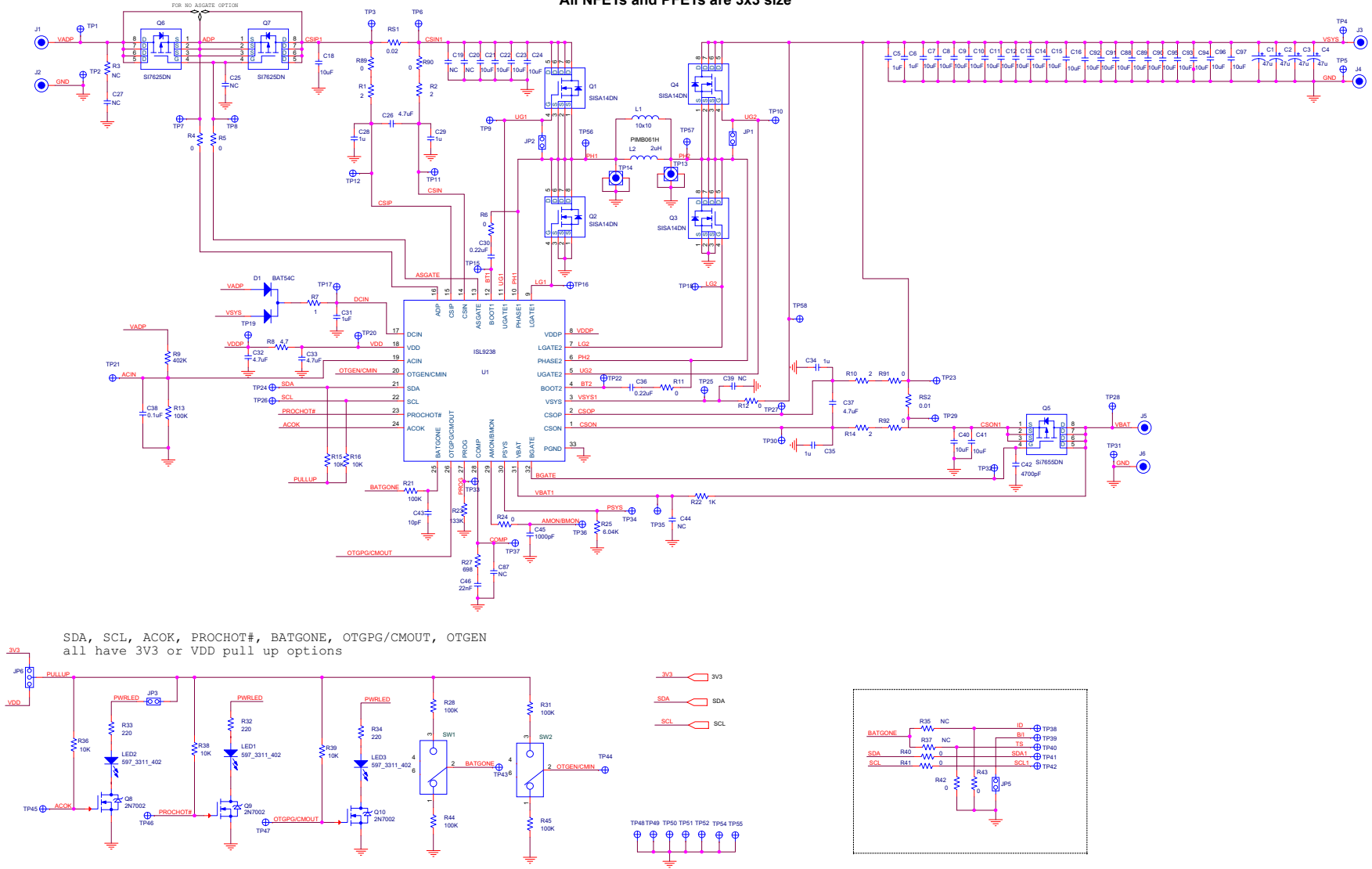


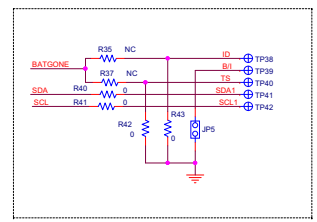
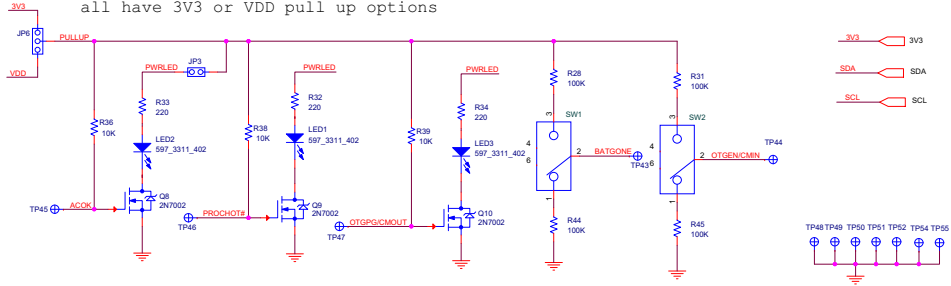
FIGURE 5. OTG FUNCTION ENABLE

ISL9238EVAL1Z Schematic

All NFETs and PFETs are 3x3 size



SDA, SCL, ACOK, PROCHOT#, BATGONE, OTGPG/CMOUT, OTGEN all have 3V3 or VDD pull up options



For battery connector connection

FIGURE 6. ISL9238EVAL1Z BOARD SCHEMATIC

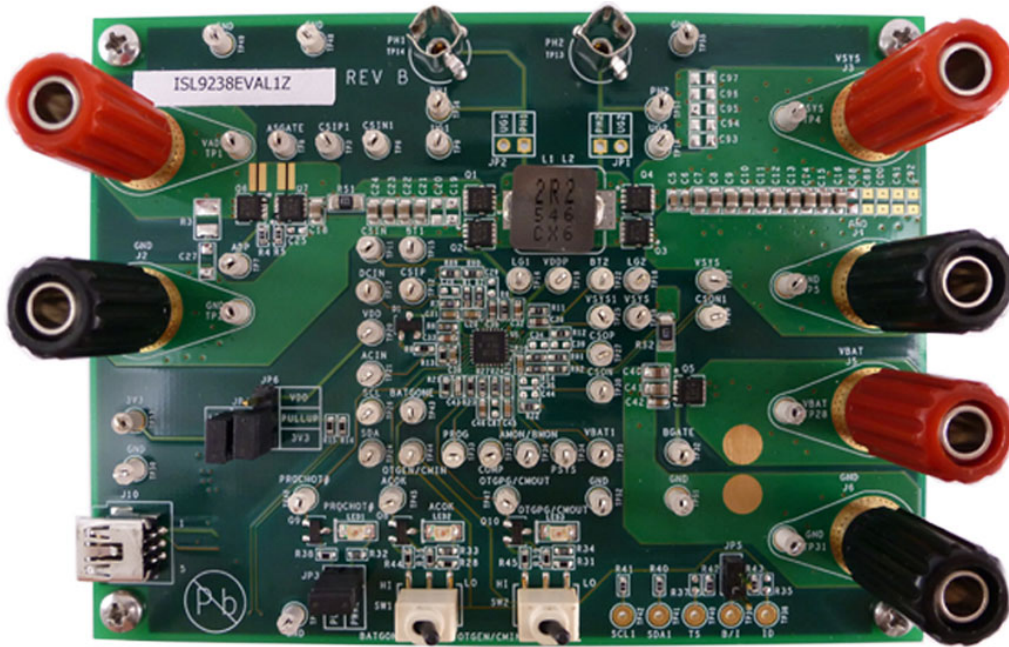


FIGURE 7. TOP OF BOARD

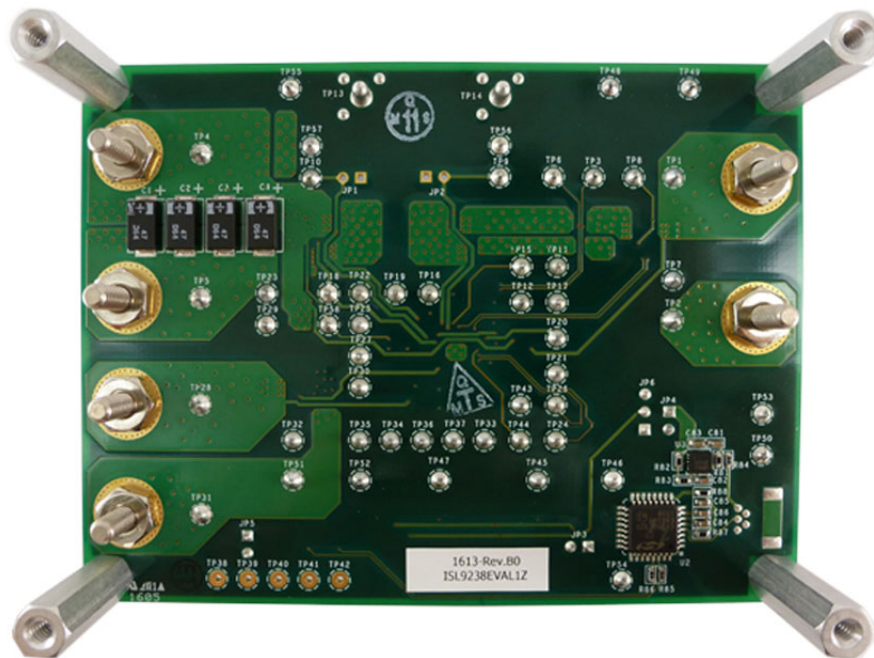


FIGURE 8. BOTTOM OF BOARD

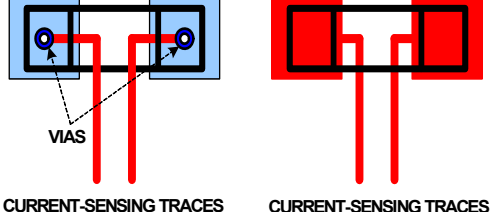
Bill of Materials

QTY	REFERENCE DESIGNATOR	DESCRIPTION	MANUFACTURER	MANUFACTURER PART
1	SEE LABEL-RENAME BOARD	PWB-PCB, ISL9237EVAL1Z, REV.B, ROHS	IMAGINEERING INC	ISL9237EVAL1ZREVBPCB
4	C1, C2, C3, C4	CAP-POSCAP, SMD, 7.3x4.3x1.9, 47µF, 20V, 20%, 55mΩ, ROHS	SANYO	20TQC47MYF
1	C43	CAP, SMD, 0603, 10pF, 50V, 10%, NP0, ROHS	VENKEL	C0603COG500-100KDE
2	C45, C82	CAP, SMD, 0603, 1000pF, 16V, 10%, X7R, ROHS	VENKEL	C0603X7R160102KNE
4	C38, C84, C85, C86	CAP, SMD, 0603, 0.1µF, 25V, 10%, X7R, ROHS	MURATA	GRM188R71E104KA01D
9	C5, C6, C28, C29, C31, C34, C35, C81, C83	CAP, SMD, 0603, 1µF, 25V, 10%, X5R, ROHS	MURATA	GRM188R61E105KA12D
1	C46	CAP, SMD, 0603, 0.022µF, 25V, 10%, X7R, ROHS	MURATA	GRM188R71E223KA01J
2	C30, C36	CAP, SMD, 0603, 0.22µF, 25V, 10%, X7R, ROHS	TDK	C1608X7R1E224K
1	C42	CAP, SMD, 0603, 4700pF, 16V, 10%, X7R, ROHS	VENKEL	C0603X7R160-472KNE
4	C26, C32, C33, C37	CAP, SMD, 0603, 4.7µF, 10V, 10%, X5R, ROHS	VENKEL	CR0603-16W-4701FT
0	C87	CAP, SMD, 0603, DNP-PLACE HOLDER, ROHS		
17	C7-C16, C18, C21, C22, C23, C24, C40, C41	CAP, SMD, 0805, 10µF, 25V, 10%, X5R, ROHS	TDK	C2012X5R1E106K
1	L1	PWR CHOKE COIL, SMD, 6.95x6.6, 2.2µH, 10A, 20%, ROHS	CYNTEC CO., LTD.	PIMB063T-2R2MS-01
3	J1, J3, J5	CONN-GEN, BIND.POST, INSUL-RED, THMBNUT-GND	JOHNSON COMPONENTS	111-0702-001
3	J2, J4, J6	CONN-GEN, BIND.POST, INSUL-BLK, THMBNUT-GND	JOHNSON COMPONENTS	111-0703-001
2	TP13, TP14	CONN-SCOPE PROBE TEST PT, COMPACT, PCB MNT, ROHS	TEKTRONIX	131-4353-00
51	TP1-TP12, TP15-TP37, TP43-TP58	CONN-MINI TEST POINT, VERTICAL, WHITE, ROHS	KEYSTONE	5002
1	J10	CONN-USB MINI-B RECEPTACLE, TH, 5 CIRCUIT, R/A, ROHS	MOLEX	54819-0519
1	JP6	CONN-HEADER, 1x3, BREAKAWY 1x36, 2.54mm, ROHS	BERG/FCI	68000-236HLF
3	JP3, JP4, JP5	CONN-HEADER, 1x2, RETENTIVE, 2.54mm, 0.230x0.120, ROHS	BERG/FCI	69190-202HLF
3	JP3, JP4, JP6-Pins 1-2	CONN-JUMPER, SHORTING, 2PIN, BLACK, GOLD, ROHS	SULLINS	SPC02SYAN
1	D1	DIODE-RECTIFIER, SMD, SOT23, 30V, 200mA, DUAL DIODE, ROHS		BAT54C-7-F-T
3	LED1, LED2, LED3	LED, SMD, 1206, GREEN, 75mW, 3mcd, 567nm, ROHS	DIALIGHT	597-3311-407NF
1	U2	IC-USB MICROCONTROLLER, 32P, LQFP, PROGRAMMED, ROHS	SILICON LABORATORIES	C8051F320-GQ
1	U3	IC-ADJ.V, 1A LDO REGULATOR, 10P, DFN, 3x3, ROHS	RENESAS	ISL80101IRAJZ
1	U1	IC-NOTEBOOK BATTERY CHARGER, 32P, QFN, 4x4, ROHS	RENESAS	ISL9238HRTZ
3	Q8, Q9, Q10	TRANSISTOR, N-CHANNEL, 3LD, SOT-23, 60V, 115mA, ROHS	DIODES, INC.	2N7002-7-F

Bill of Materials

QTY	REFERENCE DESIGNATOR	DESCRIPTION	MANUFACTURER	MANUFACTURER PART
3	Q5, Q6, Q7 (ALT: SISS27DN-T1-GE3-T)	TRANSISTOR-MOS, P-CHANNEL, -30V, -35A, 8P, PWRPAK, ROHS	VISHAY	SI7625DN-T1-GE3
4	Q1, Q2, Q3, Q4	TRANSISTOR-MOS, N-CHANNEL, 8P, PWRPAK, 30V, 20A, ROHS	VISHAY	SISA14DN-T1-GE3
5	R1, R2, R7, R10, R14	RES, SMD, 0603, 2 Ω , 1/10W, 1%, TF, ROHS	YAGEO	9C06031A2R00FGHFT
1	R8	RES, SMD, 0603, 4.7 Ω , 1/10W, 1%, TF, ROHS	VENKEL	CR0603-10W-4R70FT
17	R4, R5, R6, R11, R12, R24, R40, R41, R42, R43, R84, R85, R86, R89, R90, R91, R92	RES, SMD, 0603, 0 Ω , 1/10W, TF, ROHS	VENKEL	CR0603-10W-000T
4	R22, R83, R87, R88	RES, SMD, 0603, 1k, 1/10W, 1%, TF, ROHS	PANASONIC	ERJ-3EKF1001V
6	R15, R16, R36, R38, R39, R81	RES, SMD, 0603, 10k, 1/10W, 1%, TF, ROHS	VENKEL	CR0603-10W-1002FT
6	R13, R21, R28, R31, R44, R45	RES, SMD, 0603, 100k, 1/10W, 1%, TF, ROHS	VENKEL	CR0603-10W-1003FT
1	R23	RES, SMD, 0603, 133k, 1/10W, 1%, TF, ROHS	VENKEL	CR0603-10W-1333FT
3	R32, R33, R34	RES, SMD, 0603, 220 Ω , 1/10W, 1%, TF, ROHS	YAGEO	RC0603FR-07220RL
1	R9	RES, SMD, 0603, 402k, 1/16W, 1%, TF, ROHS	PANASONIC	ERJ-3EKF4023V
1	R82	RES, SMD, 0603, 5.62k, 1/10W, 1%, TF, ROHS	PANASONIC	ERJ-3EKF5621V
1	R25	RES, SMD, 0603, 6.04k, 1/10W, 1%, TF, ROHS	VENKEL	CR0603-10W-6041FT
1	R27	RES, SMD, 0603, 698 Ω , 1/10W, 1%, TF, ROHS	PANASONIC	ERJ-3EKF6980V
1	RS2	RES-CURR.SENSE, SMD, 1206, 0.01 Ω , 1W, 1%, 75ppm, ROHS	VISHAY/DALE	WSLP1206R0100FEA
1	RS1	RES-CURR.SENSE, SMD, 1206, 0.02 Ω , 1W, 1%, 75ppm, ROHS	VISHAY/DALE	WSLP1206R0200FEA
2	SW1, SW2	SWITCH-TOGGLE, SMD, 6PIN, SPDT, 2POS, ON-NONE-ON, ROHS	ITT INDUSTRIES/ C&K DIVISION	GT11MSCBE
4	Four corners	SCREW, 4-40x1/4in, PHILLIPS, PANHEAD, STAINLESS, ROHS	BUILDING FASTENERS	PMSSS 440 0025 PH
4	Four corners	STANDOFF, 4-40x3/4in, F/F, HEX, ALUMINUM, 0.25 OD, ROHS	KEYSTONE	2204
1	Place assembly in bag	BAG, STATIC, 5x8, ZIPLOC, ROHS	RENESAS	212403-013
0	C19, C20, C25, C27, C39, C44, C88-C97	DO NOT POPULATE OR PURCHASE		
0	JP1, JP2	DO NOT POPULATE OR PURCHASE		
0	L2	DO NOT POPULATE OR PURCHASE		
0	R3, R35, R37	DO NOT POPULATE OR PURCHASE		
0	TP38-TP42	DO NOT POPULATE OR PURCHASE		
1	AFFIX TO BACK OF PCB	LABEL-DATE CODE_LINE 1: YRWK/REV#, LINE 2: BOM NAME	RENESAS	LABEL-DATE CODE
1	RENAME PCB TO: ISL9238EVAL1Z.	LABEL, TO RENAME BOARD	RENESAS	LABEL-RENAME BOARD

PCB Layout Guidelines

PIN NUMBER	PIN NAME	LAYOUT GUIDELINES
BOTTOM PAD 33	GND	Connect the ground pad to the ground plane through a low impedance path. Use at least five vias to connect to the ground planes in the PCB to ensure sufficient thermal dissipation directly under the IC.
1	CSON	<p>Run two dedicated traces with sufficient width parallel to (close to each other to minimize the loop area) the two terminals of the battery current-sensing resistor to the IC. Place the differential mode and common-mode RC filter components in the general proximity of the controller.</p> <p>Route the current-sensing traces through vias to connect the center of the pads, or route the traces into the pads from the inside of the current-sensing resistor. The following drawings show the two preferred ways of routing current-sensing traces.</p> 
2	CSOP	
3	VSYS	Signal pin that provides feedback for the system bus voltage. Place the optional RC filter in the general proximity of the controller. Run a dedicated trace from the system bus to the pin and do not route near the switching traces. Do not share the same trace with the signal routing to the DCIN pin OR diodes.
4	BOOT2	Switching pin. Place the bootstrap capacitor in the general proximity of the controller. Use sufficiently wide trace. Do not allow any sensitive analog signal traces to cross over or get close to this pin.
5	UGATE2	<p>Run the UGATE2 and PHASE2 traces in parallel with sufficient width. Do not allow any sensitive analog signal traces to cross over or get close to this pin. Renesas recommends routing the PHASE2 trace to the high-side MOSFET source pin instead of general copper.</p> <p>Place the IC close to the switching MOSFET's gate terminals and keep the gate drive signal traces short for a clean MOSFET drive. The IC can be placed on the opposite side of the switching MOSFETs.</p> <p>Place the output capacitors as close as possible to the switching high-side MOSFET drain and the low-side MOSFET source. Use the shortest PCB trace connection. Place the capacitors on the same PCB layer as the MOSFETs instead of on different layers and using vias to make the connection.</p> <p>Place the inductor terminal to the switching high-side MOSFET drain and low-side MOSFET source terminal as close as possible. Minimize this phase node area to lower the electrical and magnetic field radiation, but make this phase node area large enough to carry the current. Place the inductor and the switching MOSFETs on the same layer of the PCB.</p>
6	PHASE2	
7	LGATE2	Switching pin. Run the LGATE2 trace parallel to the UGATE2 and PHASE2 traces on the same PCB layer. Use sufficient width. Do not allow any sensitive analog signal traces to cross over or get close to this pin.
8	VDDP	Place the decoupling capacitor in the general proximity of the controller. Run the trace connecting to the VDD pin with sufficient width.
9	LGATE1	Switching pin. Run the LGATE1 trace parallel to the UGATE1 and PHASE1 traces on the same PCB layer. Use sufficient width. Do not allow any sensitive analog signal traces to cross over or get close to this pin.

PCB Layout Guidelines (Continued)

PIN NUMBER	PIN NAME	LAYOUT GUIDELINES
10	PHASE1	Run the PHASE1 and UGATE1 traces in parallel with sufficient width. Do not allow any sensitive analog signal traces to cross over or get close to these pins. Renesas recommends routing the PHASE1 trace to the high-side MOSFET source pin instead of general copper.
11	UGATE1	<p>Place the IC close to the switching MOSFET's gate terminals and keep the gate drive signal traces short for a clean MOSFET drive. The IC can be placed on the opposite side of the switching MOSFETs.</p> <p>Place the input capacitors as close as possible to the switching high-side MOSFET drain and the low-side MOSFET source. Use the shortest PCB trace connection. Place the input capacitors on the same PCB layer as the MOSFETs instead of on different layers and using vias to make the connection.</p> <p>Place the inductor terminal to the switching high-side MOSFET drain and low-side MOSFET source terminal as close as possible. Minimize the phase node area to lower the electrical and magnetic field radiation, but make this phase node area large enough to carry the current. Place the inductor and the switching MOSFETs on the same layer of the PCB.</p>
12	BOOT1	Switching pin. Place the bootstrap capacitor in the general proximity of the controller. Use a sufficiently wide trace. Do not allow any sensitive analog signal traces to cross over or get close to this pin.
13	ASGATE	Run this trace with sufficient width parallel to the ADP pin trace.
14	CSIN	Run two dedicated traces with sufficient width parallel to (close to each other to minimize the loop area) the two terminals of the adapter current-sensing resistor to the IC. Place the differential mode and common-mode RC filter components in the general proximity of the controller.
15	CSIP	<p>Route the current-sensing traces through vias to connect the center of the pads or route the traces into the pads from the inside of the current-sensing resistor. The following drawings show the two preferred ways of routing current-sensing traces.</p> <div style="text-align: center;"> <p>The left diagram shows two red traces routing through vias to the center of the pads. The right diagram shows two red traces routing into the pads from the inside. Both diagrams show two red traces connected to a resistor structure.</p> </div>
16	ADP	Run this trace with sufficient width parallel to the ASGATE pin trace.
17	DCIN	Place the OR diodes and the RC filter in the general proximity of the controller. Run the VADP trace and VSYS trace to the OR diodes with sufficient width.
18	VDD	Place the RC filter connecting with the VDDP pin in general proximity of the controller. Run the trace connecting to VDDP pin with sufficient width.
19	ACIN	Place the voltage divider resistors and the optional decoupling capacitor in the general proximity of the controller.
20	OTGEN/CMIN	No special consideration.
21	SDA	Digital pins. No special consideration. Run the SDA and SCL traces in parallel.
22	SCL	
23	PROCHOT#	Digital pin, open-drain output. No special consideration.
24	ACOK	
25	BATGONE	Digital pin. Place the 100kΩ resistor series in the BATGONE signal trace and the optional decoupling capacitor in the general proximity of the controller.
26	OTGPG/CMOUT	Digital pin, open-drain output. No special consideration.
27	PROG	Signal pin. Place the PROG programming resistor in the general proximity of the controller.
28	COMP	Place the compensation components in the general proximity of the controller. Do not allow any switching signals to cross over or get close to this pin.

PCB Layout Guidelines (Continued)

PIN NUMBER	PIN NAME	LAYOUT GUIDELINES
29	AMON/BMON	No special consideration. Place the optional RC filter in the general proximity of the controller.
30	PSYS	Signal pin, current source output. No special consideration.
31	VBAT	Place the optional RC filter in the general proximity of the controller. Run a dedicated trace from the battery positive connection point to the IC.
32	BGATE	Use a sufficiently wide trace from the IC to the BGATE MOSFET gate. Place the capacitor from BGATE to ground close to the MOSFET.

Board Layout

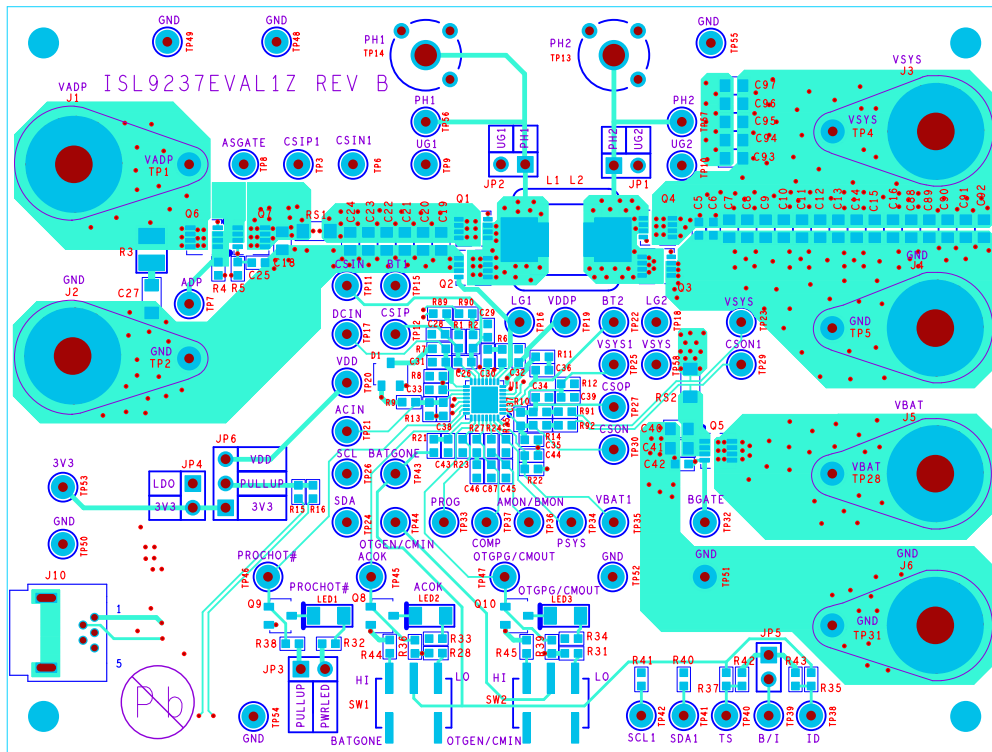


FIGURE 9. TOP LAYER

Board Layout (Continued)

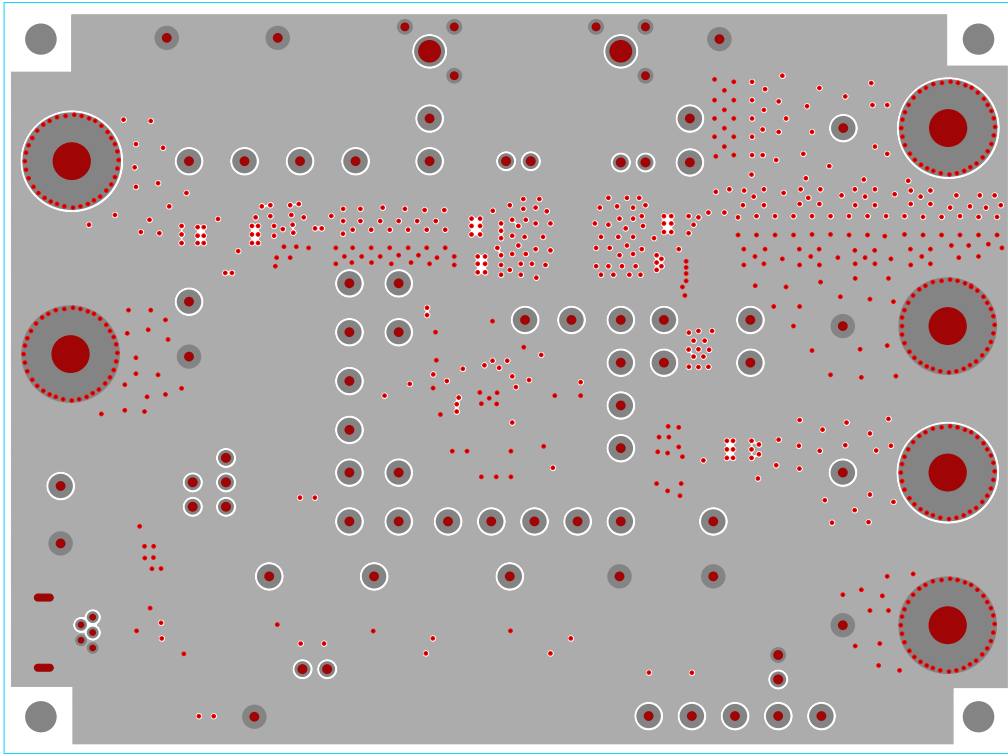


FIGURE 10. INNER LAYER 1

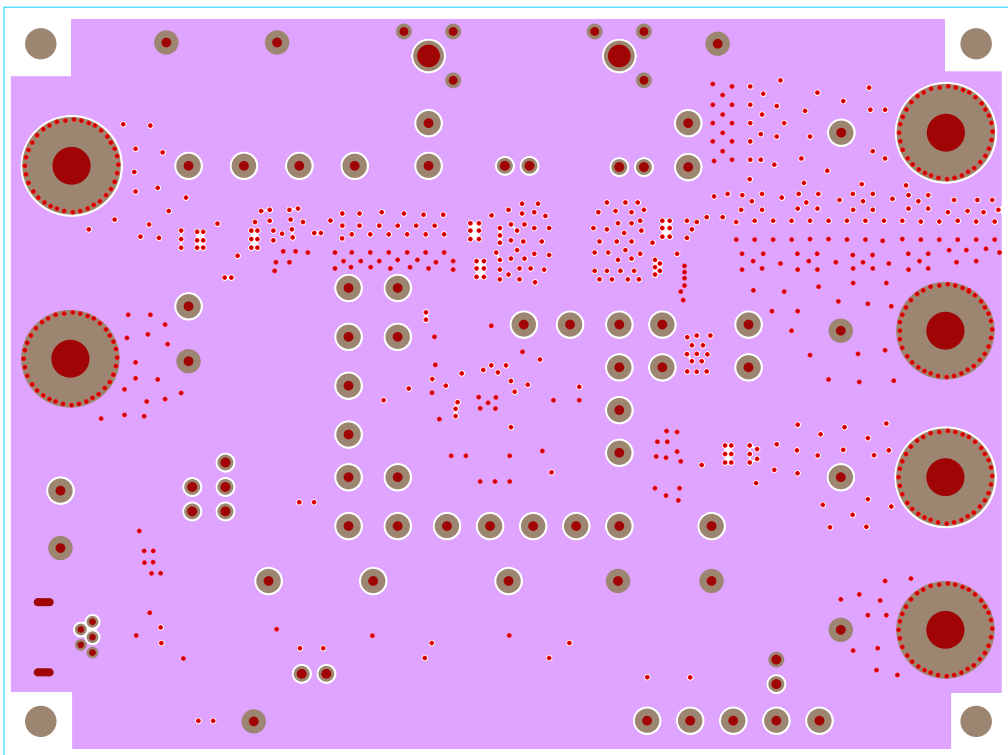


FIGURE 11. INNER LAYER 2

Board Layout (Continued)

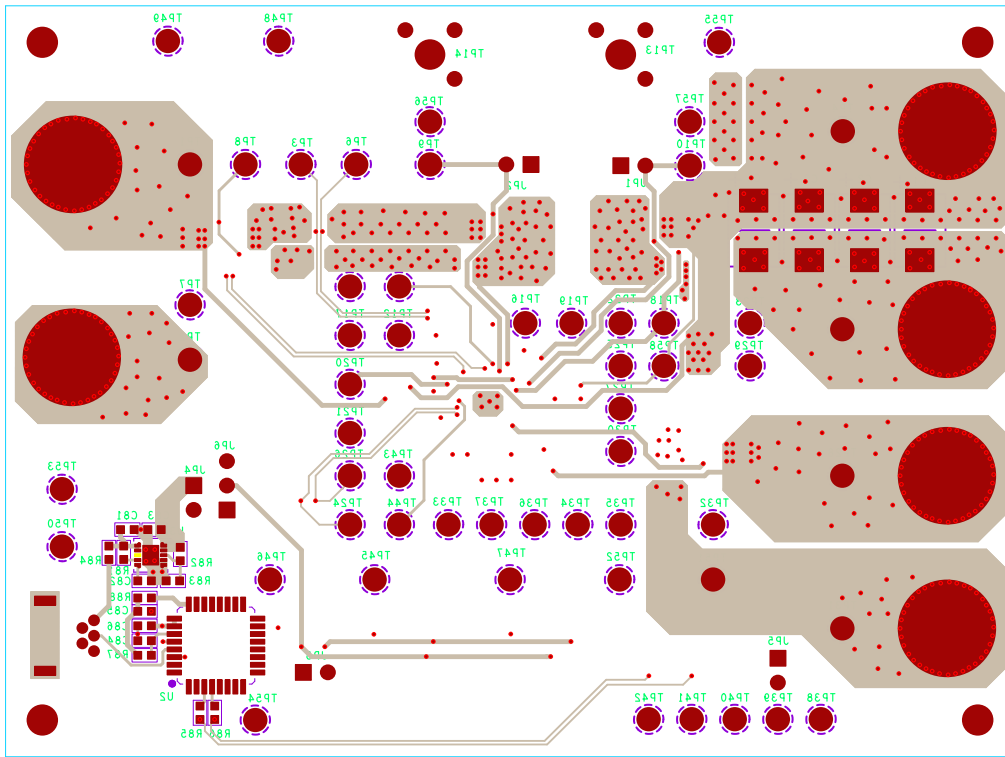


FIGURE 12. BOTTOM LAYER

Typical Performance

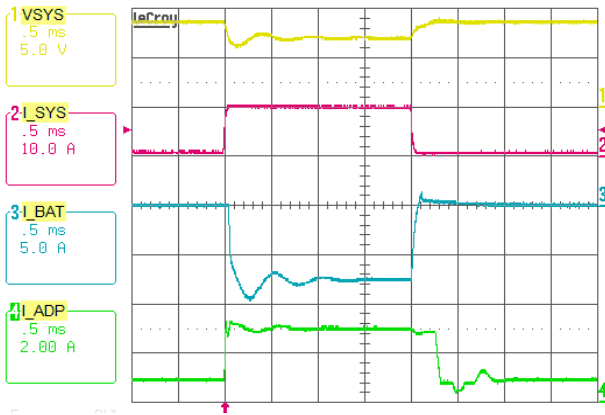


FIGURE 13. BOOST MODE, OUTPUT VOLTAGE LOOP TO ADAPTER CURRENT LOOP TRANSITION. $V_{ADP} = 5V$, $MAXSYSTEMVOLTAGE = 8.496V$, $V_{BAT} = 7V$, SYSTEM LOAD 0.5A TO 10A STEP, $ADAPTERCURRENTLIMIT = 3A$, $CHARGECURRENT = 0A$

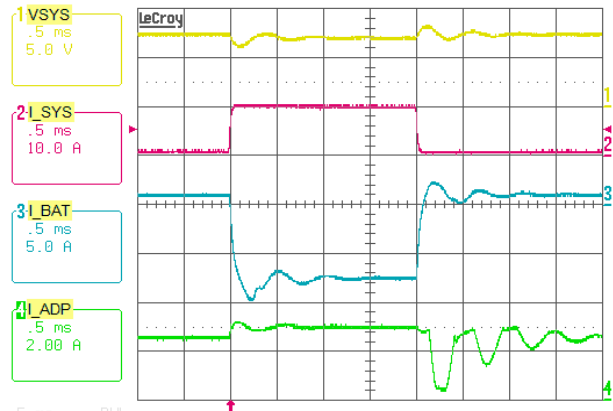


FIGURE 14. BOOST MODE, CHARGING CURRENT LOOP TO ADAPTER CURRENT LOOP TRANSITION. $V_{ADP} = 5V$, $MAXSYSTEMVOLTAGE = 8.496V$, $V_{BAT} = 7V$, SYSTEM LOAD 0.5A TO 10A STEP, $ADAPTERCURRENTLIMIT = 3A$, $CHARGECURRENT = 1A$

Typical Performance (Continued)

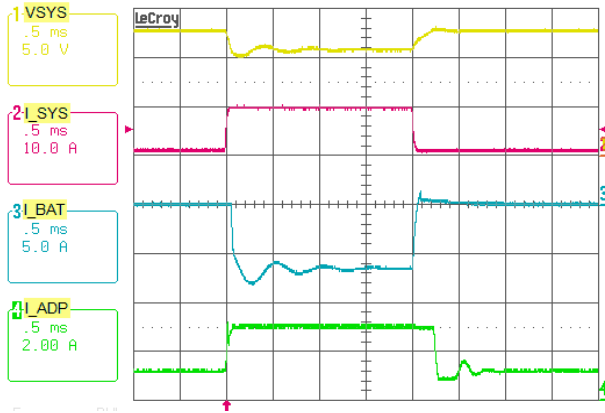


FIGURE 15. BUCK-BOOST MODE, OUTPUT VOLTAGE LOOP TO ADAPTER CURRENT LOOP TRANSITION. $V_{ADP} = 12V$, $MAXSYSTEMVOLTAGE = 12.6V$, $V_{BAT} = 11V$, SYSTEM LOAD 1A TO 10A STEP, $ADAPTERCURRENTLIMIT = 3A$, $CHARGECURRENT = 0A$

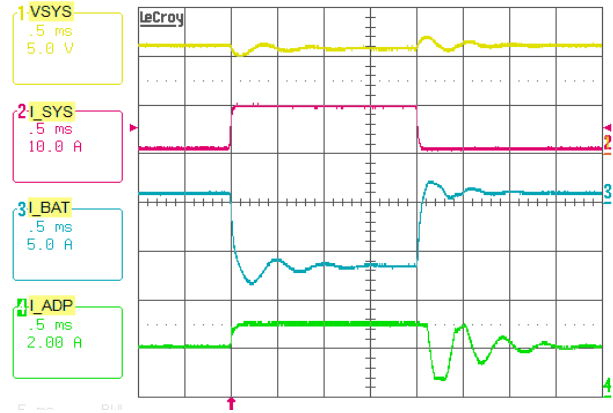


FIGURE 16. BUCK-BOOST MODE, CHARGING CURRENT LOOP TO ADAPTER CURRENT LOOP TRANSITION. $V_{ADP} = 12V$, $MAXSYSTEMVOLTAGE = 12.6V$, $V_{BAT} = 11V$, SYSTEM LOAD 1A TO 10A STEP, $ADAPTERCURRENTLIMIT = 3A$, $CHARGECURRENT = 1A$

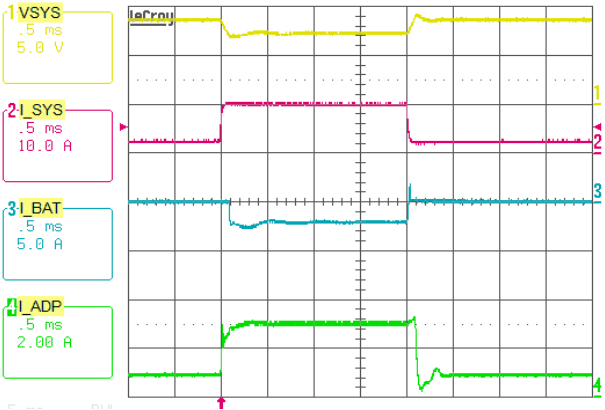


FIGURE 17. BUCK MODE, OUTPUT VOLTAGE LOOP TO ADAPTER CURRENT LOOP TRANSITION. $V_{ADP} = 20V$, $MAXSYSTEMVOLTAGE = 8.496V$, $V_{BAT} = 7V$, SYSTEM LOAD 2A TO 10A STEP, $ADAPTERCURRENTLIMIT = 3A$, $CHARGECURRENT = 0A$

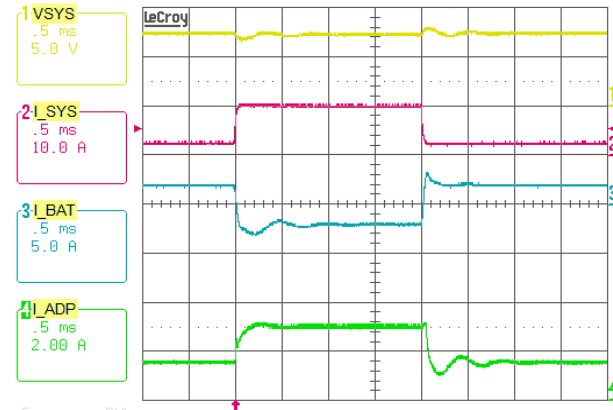


FIGURE 18. BUCK MODE, CHARGING CURRENT LOOP TO ADAPTER CURRENT LOOP TRANSITION. $V_{ADP} = 20V$, $MAXSYSTEMVOLTAGE = 8.496V$, $V_{BAT} = 7V$, SYSTEM LOAD 2A TO 10A STEP, $ADAPTERCURRENTLIMIT = 3A$, $CHARGECURRENT = 2A$

Typical Performance (Continued)

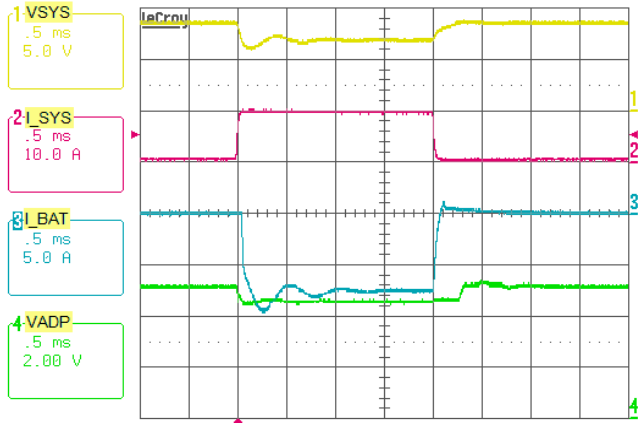


FIGURE 19. BOOST MODE, OUTPUT VOLTAGE LOOP TO INPUT VOLTAGE LOOP TRANSITION. $V_{ADP} = 5V$, $MAXSYSTEMVOLTAGE = 8.496V$, $V_{BAT} = 7V$, $VINDAC = 4.5V$, SYSTEM LOAD 0.5A TO 10A STEP, $CHARGECURRENT = 0A$

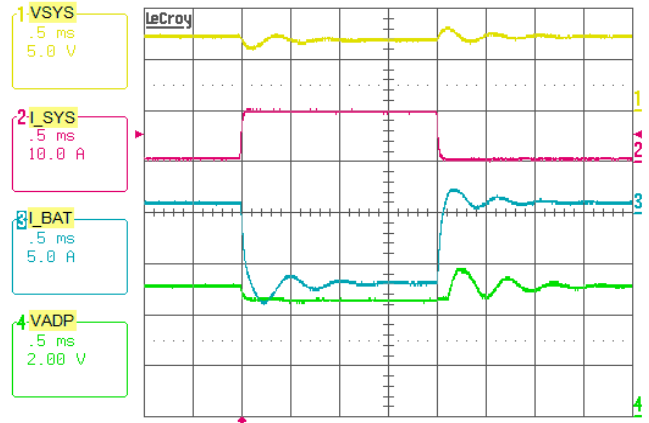


FIGURE 20. BOOST MODE, CHARGING CURRENT LOOP TO INPUT VOLTAGE LOOP TRANSITION. $V_{ADP} = 5V$, $MAXSYSTEMVOLTAGE = 8.496V$, $V_{BAT} = 7V$, $VINDAC = 4.5V$, SYSTEM LOAD 0.5A TO 10A STEP, $CHARGECURRENT = 1A$

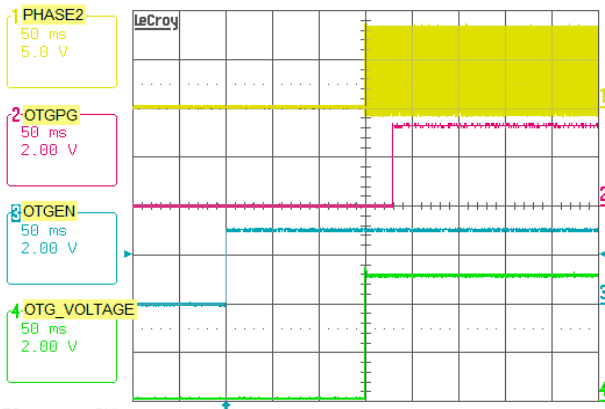


FIGURE 21. OTG MODE ENABLE, OTG ENABLE 150ms DEBOUNCE TIME

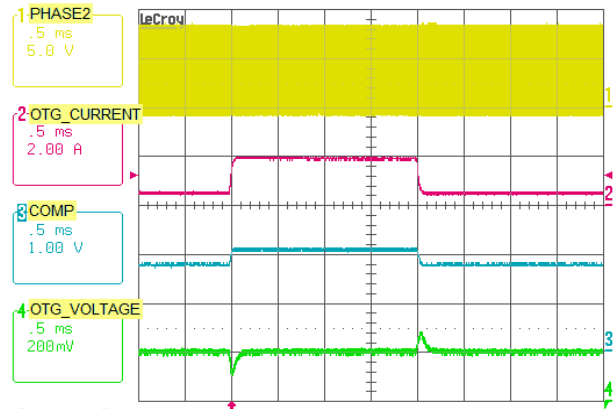


FIGURE 22. OTG MODE 0.5A TO 2A TRANSIENT LOAD, OTG VOLTAGE = 5.12V

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please visit our website to make sure you have the latest revision.

DATE	REVISION	CHANGE
Nov 14, 2018	UG074.2	Updated schematic. Added Revision History.

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Renesas Electronics Corporation

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

Renesas Electronics America Inc.

1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.
Tel: +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited

9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3
Tel: +1-905-237-2004

Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-651-700

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.

Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited

Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.

80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.

Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd.

No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India
Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd.

17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5338